



°C



	°C					
	°C					
	°C					
	°C					
	°C					
	°C					
	°C					
	°C					



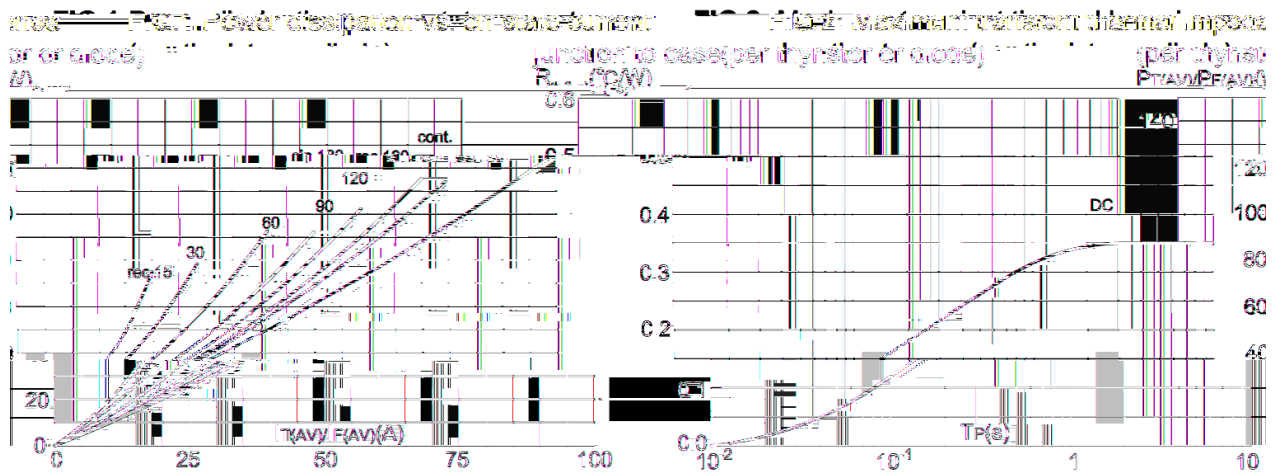


FIG.5 Gate trigger characteristics

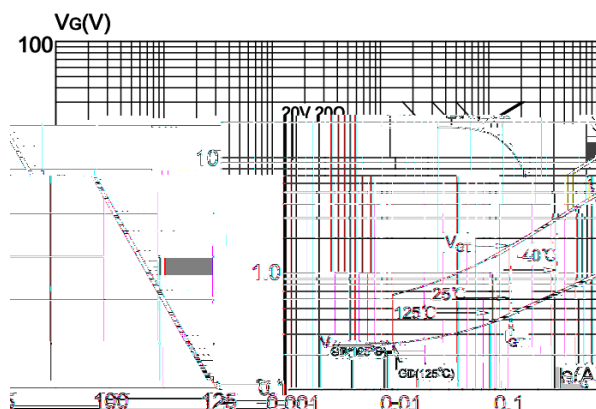


FIG.6: Forward current vs. case temperature
 $I_{F(AV)}$ (A) (per thyristor or diode)



